TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOSVI)

# SSM3J133TU

## Power Management Switch Applications

Unit: mm

	4	.5V	سالم	:. <i>.</i> _
•	- 1	.ov	uı	ive

• Low ON-resistance:  $R_{DS(ON)}$  = 88.4 m $\Omega$  (max) (@V<sub>GS</sub> = -1.5 V)

 $R_{DS(ON)} = 56.0 \text{ m}\Omega \text{ (max) (@V_{GS} = -1.8 V)}$ 

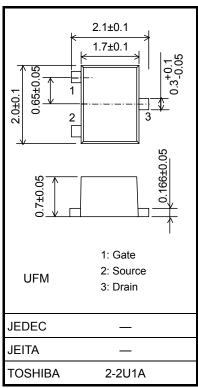
 $R_{DS(ON)} = 39.7 \text{ m}\Omega \text{ (max) (@V_{GS} = -2.5 V)}$ 

 $R_{DS(ON)} = 29.8 \text{ m}\Omega \text{ (max) (@V_{GS} = -4.5 V)}$ 

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol		Rating	Unit	
Drain-source voltage		$V_{DSS}$		-20	V	
Gate-source voltage		V <sub>GSS</sub>		± 8	V	
Drain current	DC	ΙD	(Note1)	-5.5	А	
Dialii cuiteili	Pulse	I <sub>DP</sub> (Note1)		-11.0	A	
power dissipation		P <sub>D</sub> (Note2)		500	mW	
power dissipation			t<1s	1000	11100	
Channel temperature		T <sub>ch</sub>		150	°C	
Storage temperature range		T <sub>stg</sub>		-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



weight: 6.6 mg (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

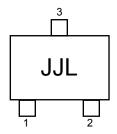
Note1: The channel temperature should not exceed 150°C during use.

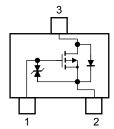
Note2: Mounted on FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{Cu Pad: } 645 \text{ mm}^2)$ 

#### Marking

## **Equivalent Circuit (Top view)**





### **Electrical Characteristics (Ta = 25°C)**

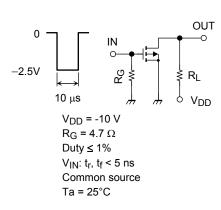
Chara	cteristics	Symbol	Test Conditions		Min	Тур.	Max	Unit
Drain source breakdown veltage	V (BR) DSS	I <sub>D</sub> = -1 mA, V <sub>GS</sub> = 0 V		-20	_	_	V	
Drain-source breakdown voltage		V (BR) DSX	I <sub>D</sub> = -1 mA, V <sub>GS</sub> = 5 V	(Note 4)	-15	_		V
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = -20 V, V <sub>GS</sub> = 0 V		_	_	-1	μА
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$		_	_	±1	μА
Gate threshold voltage		V <sub>th</sub>	$V_{DS} = -3 \text{ V}, I_{D} = -1 \text{ mA}$		-0.3	_	-1.0	V
Forward transfer admittance		Y <sub>fs</sub>	V <sub>DS</sub> = -3 V, I <sub>D</sub> = -1.0 A	(Note 3)	5.2	10.4	_	S
		I <sub>D</sub> = -3.0 A, V <sub>GS</sub> = -4.5 V	(Note 3)	_	24.9	29.8	- mΩ	
Drain-source ON-resistance		D	I <sub>D</sub> = -2.5 A, V <sub>GS</sub> = -2.5 V	(Note 3)		31.1		39.7
		R <sub>DS</sub> (ON)	I <sub>D</sub> = -1.5 A, V <sub>GS</sub> = -1.8 V	(Note 3)		38.8		56.0
			I <sub>D</sub> = -0.5 A, V <sub>GS</sub> = -1.5 V	(Note 3)		47.4		88.4
Input capacitance		C <sub>iss</sub>	.,			840		
Output capacitance		Coss	V <sub>DS</sub> = -10 V, V <sub>GS</sub> = 0 V f = 1 MHz			118		pF
Reverse transfer capacitance		C <sub>rss</sub>	T = T MMZ			99		
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD}$ = -10 V, $I_{D}$ = -2.0 A $V_{GS}$ = 0 to -2.5 V, $R_{G}$ = 4.7 $\Omega$			32		ns
	Turn-off time	t <sub>off</sub>				107		
Total gate charge		Qg	\/ 40\/ L 40 A			12.8		nC
Gate-source charge		Q <sub>gs1</sub>	$V_{DD} = -10 \text{ V}, I_D = -4.0 \text{ A},$	_	1.4	_		
Gate-drain charge		Q <sub>gd</sub>	V <sub>GS</sub> = -4.5 V		_	3.0	_	
Drain-Source forward voltage		V <sub>DSF</sub>	I <sub>D</sub> = 5.5A, V <sub>GS</sub> = 0 V	(Note3)	_	0.83	1.2	V

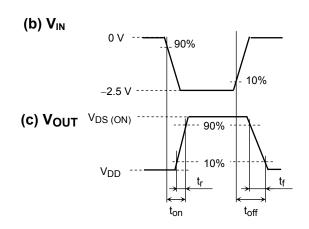
Note 3: Pulse test

Note 4: If a forward bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

## **Switching Time Test Circuit**

#### (a) Test Circuit





## **Notice on Usage**

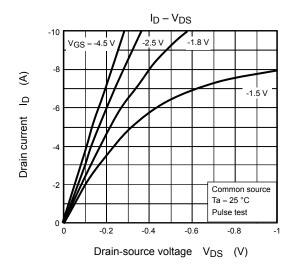
Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to be low (-1 mA for the SSM3J133TU). Then, for normal switching operation,  $V_{GS(on)}$  must be higher than  $V_{th}$ , and  $V_{GS(off)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .

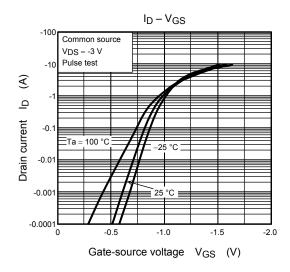
Take this into consideration when using the device.

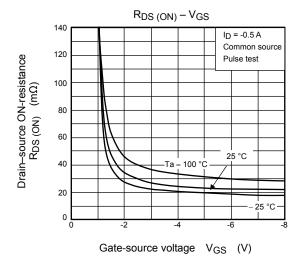
#### **Handling Precaution**

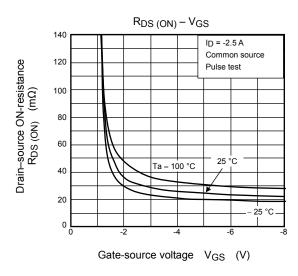
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

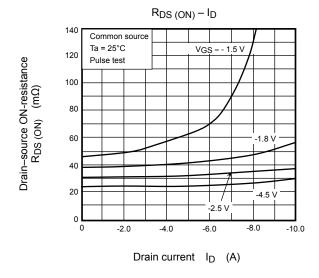
Thermal resistance R<sub>th (ch-a)</sub> and power dissipation P<sub>D</sub> vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration.

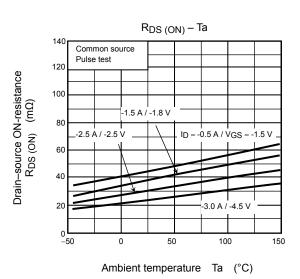




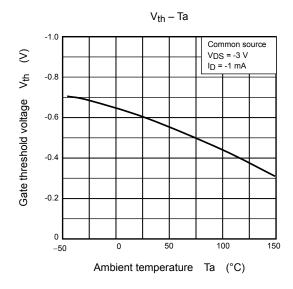


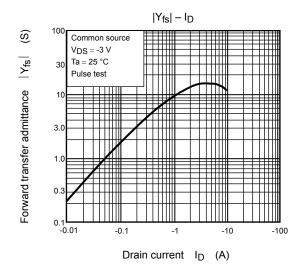


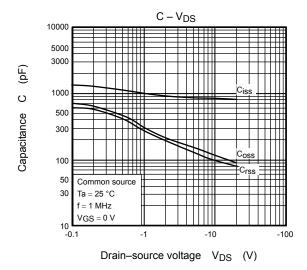


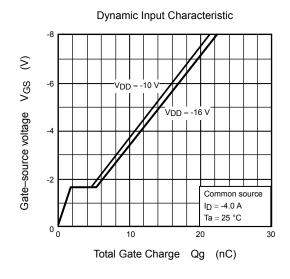


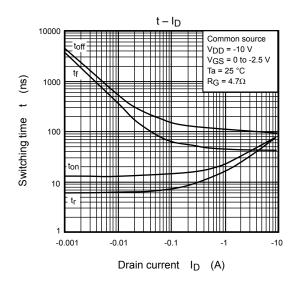
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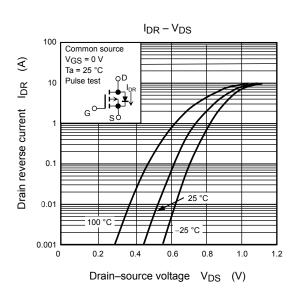




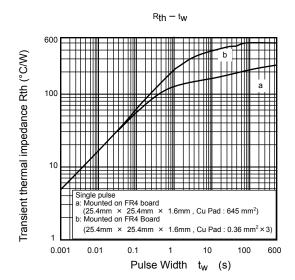


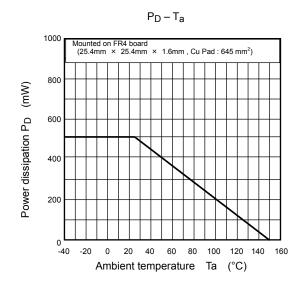






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